

(12) INTERNATIONAL APPLICATION PUBLISHED UNDER THE PATENT COOPERATION TREATY (PCT)

(19) World Intellectual Property Organization  
International Bureau



(43) International Publication Date  
1 June 2006 (01.06.2006)

PCT

(10) International Publication Number  
**WO 2006/057420 A1**

(51) International Patent Classification:  
**H01L 51/50 (2006.01) C09K 11/06 (2006.01)**

(81) Designated States (unless otherwise indicated, for every kind of national protection available): AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KM, KN, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, LY, MA, MD, MG, MK, MN, MW, MX, MZ, NA, NG, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RU, SC, SD, SE, SG, SK, SL, SM, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, YU, ZA, ZM, ZW

(21) International Application Number:  
**PCT/JP2005/021933**

(22) International Filing Date:  
**22 November 2005 (22.11.2005)**

(25) Filing Language: **English**

(26) Publication Language: **English**

(30) Priority Data:  
**2004-342717 26 November 2004 (26.11.2004) JP**

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(84) Designated States (unless otherwise indicated, for every kind of regional protection available): ARIPO (BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW), Eurasian (AM, AZ, BY, KG, KZ, MD, RU, TJ, TM), European (AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LT, LU, LV, MC, NL, PL, PT, RO, SE, SI, SK, TR), OAPI (BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG).

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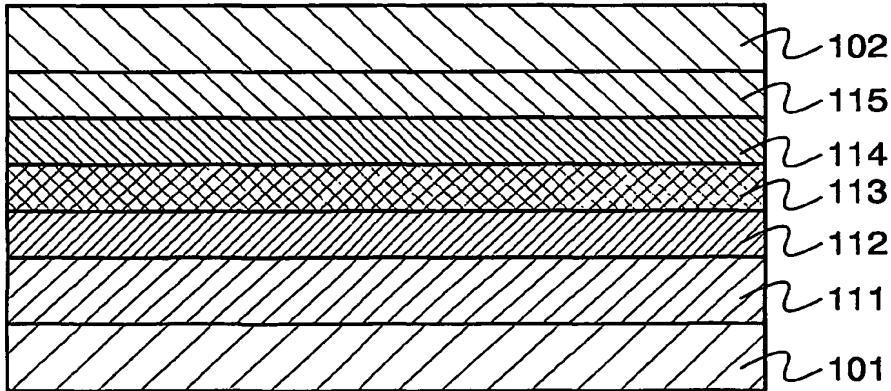
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Published:

— with international search report

For two-letter codes and other abbreviations, refer to the "Guidance Notes on Codes and Abbreviations" appearing at the beginning of each regular issue of the PCT Gazette.

(54) Title: **LIGHT-EMITTING ELEMENT, LIGHT-EMITTING DEVICE, AND ELECTRONIC DEVICE**



(57) Abstract: It is an object of the present invention to provide a light-emitting element capable of reducing malfunction due to oxidation and crystallization of a compound. According to one aspect of the present invention, a light-emitting element has a first electrode and a second electrode, a first layer and a second layer formed between the first electrode and the second electrode, wherein the first layer contains an anthracene derivative and a substance that shows electron acceptability to the anthracene derivative, wherein the second layer contains a light emitting substance. According to one aspect of a light-emitting device of the present invention, any one of the above light-emitting elements is used as a pixel or a light source.